

# **Device Modeling Report**

COMPONENTS:

DIODE/ GENERAL PURPOSE RECTIFIER/ PROFESSIONAL

PART NUMBER: CRH01

MANUFACTURER: TOSHIBA



**Bee Technologies Inc.**

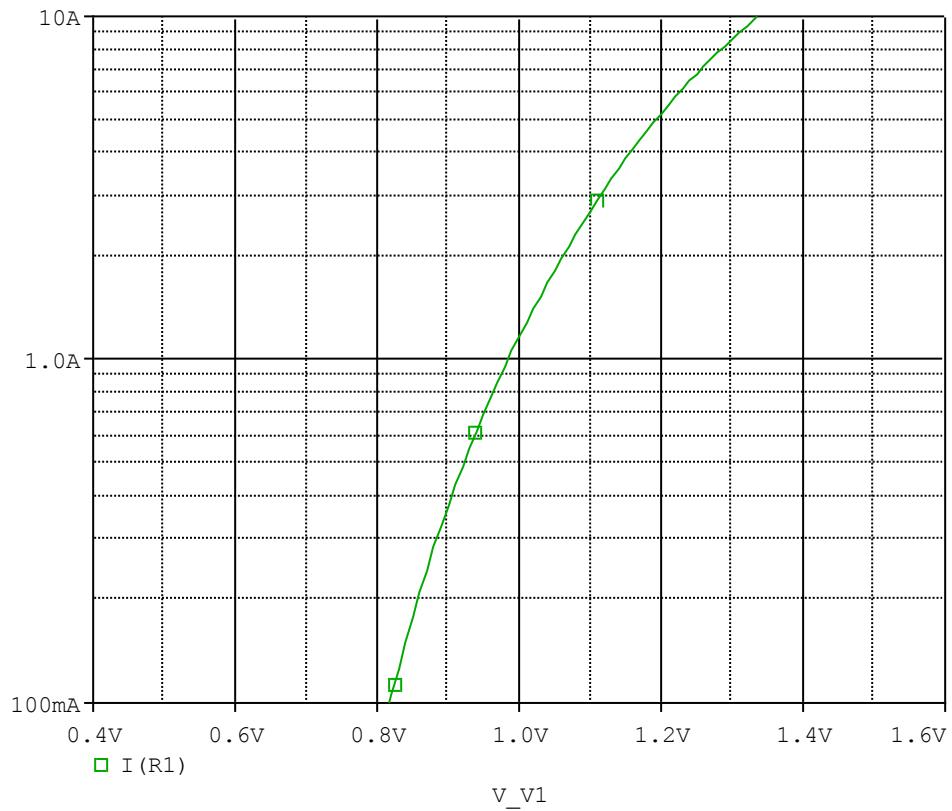
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## DIODE MODEL PARAMETERS

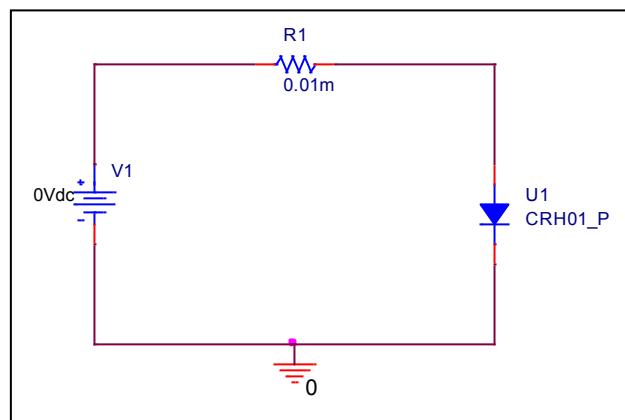
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

## Forward Current Characteristic

Circuit Simulation Result

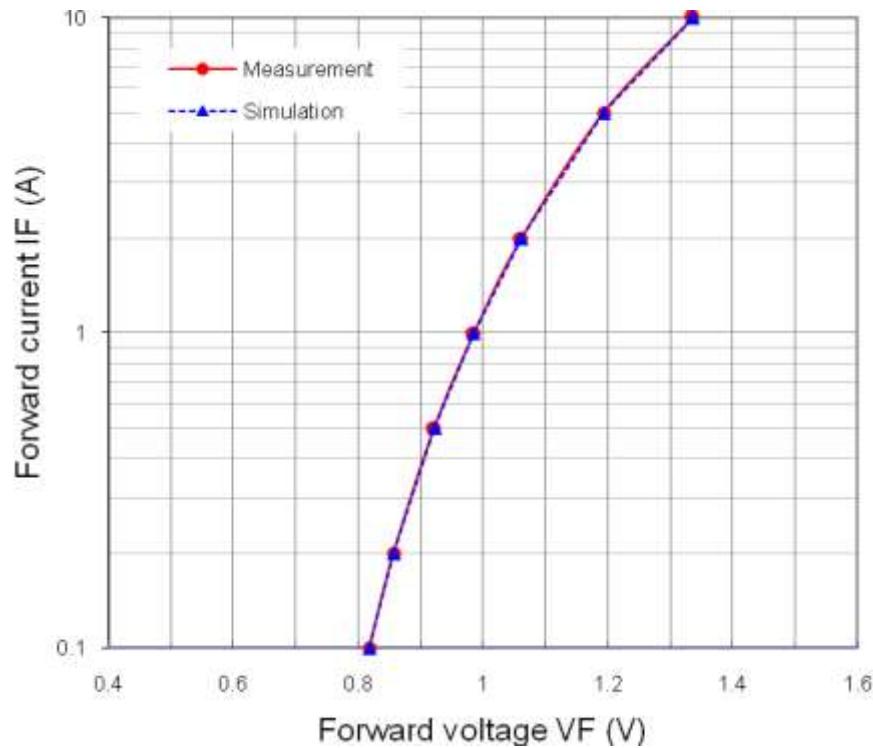


Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

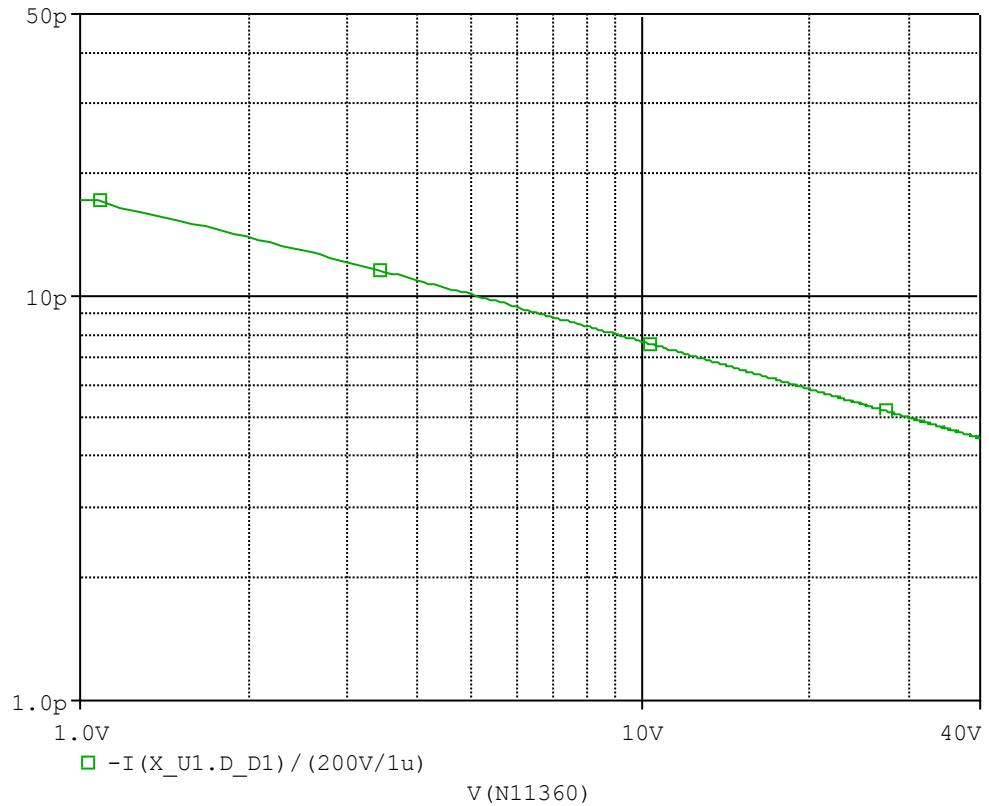


Simulation Result

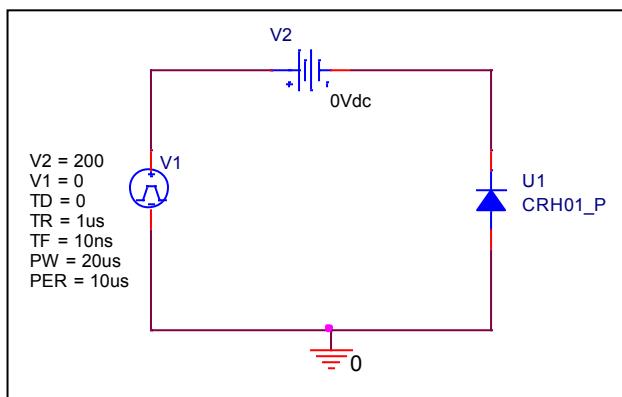
Ifwd (A)	Vfwd (V)		%Error
	Measurement	Simulation	
0.1	0.818	0.817	-0.10
0.2	0.857	0.857	0.00
0.5	0.921	0.922	0.10
1	0.985	0.984	-0.06
2	1.061	1.061	0.00
5	1.193	1.193	0.00
10	1.336	1.336	0.00

## Capacitance Characteristic

### Circuit Simulation Result

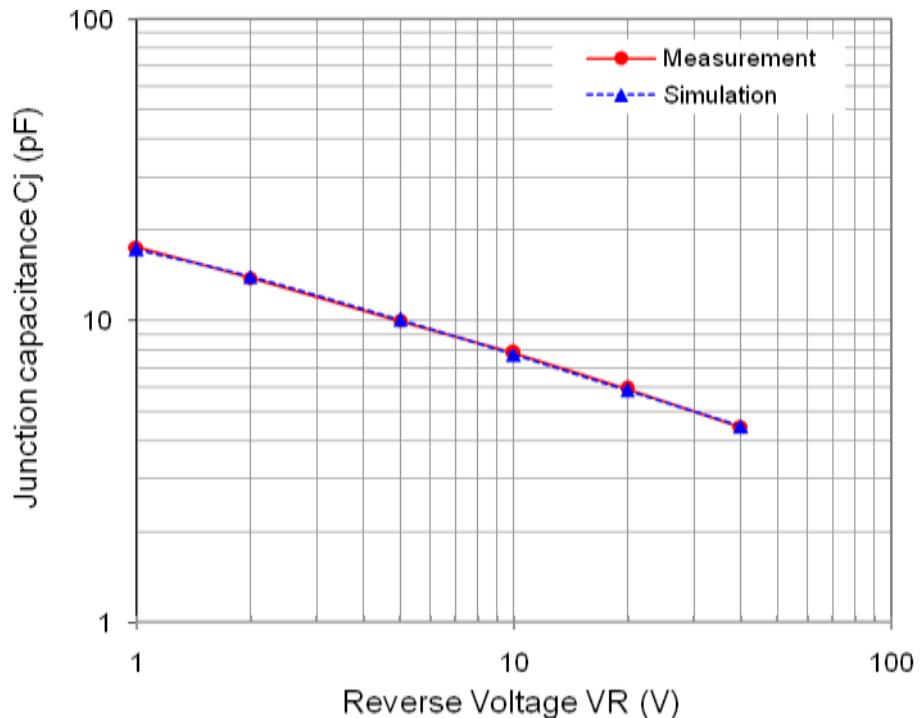


### Evaluation Circuit



## Comparison Graph

Circuit Simulation Result

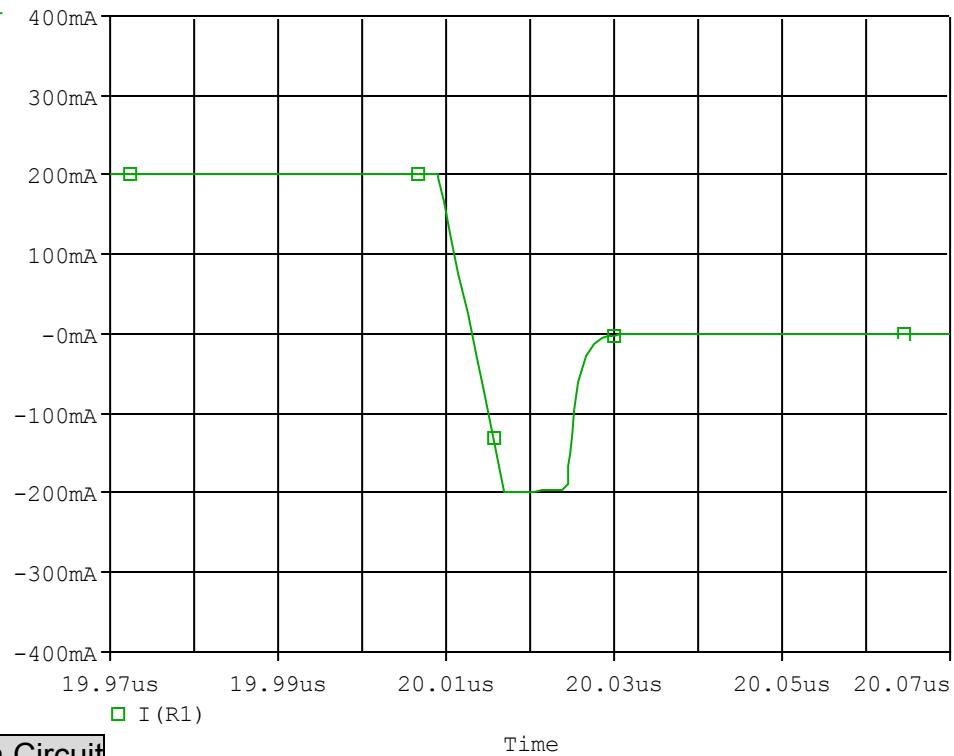


Simulation Result

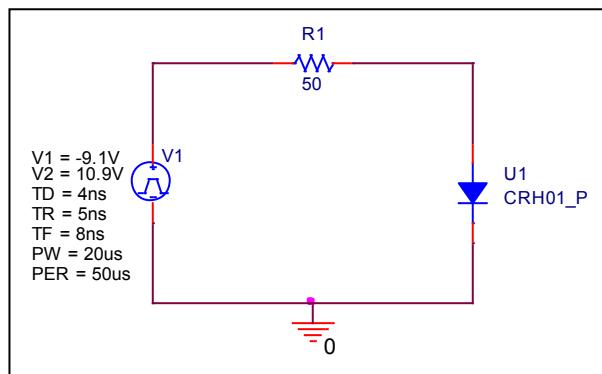
Vrev (V)	Cj (pF)		%Error
	Measurement	Simulation	
1	17.557	17.258	-1.70
2	13.852	14.002	1.08
5	10.010	10.073	0.63
10	7.808	7.724	-1.08
20	5.958	5.878	-1.34
40	4.445	4.456	0.25

## Reverse Recovery Characteristic

Circuit Simulation Result



Evaluation Circuit

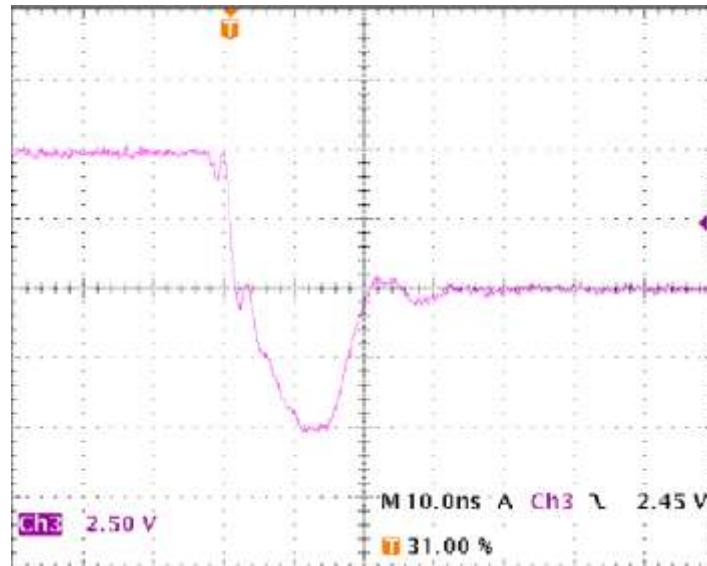


## Compare Measurement vs. Simulation

		Measurement	Simulation	%Error
trj	ns	10.00	9.66	-3.36
trb	ns	5.80	5.91	1.93
trr	ns	15.80	15.58	-1.42

## Reverse Recovery Characteristic

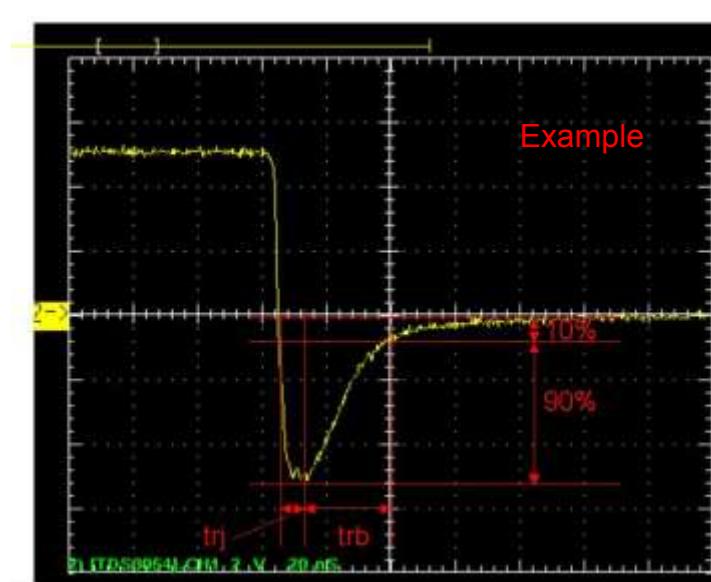
## Reference



Trj =10.00(ns)

Trb= 5.80 (ns)

Conditions: Ifwd=0.2A,Irev=0.2A, RI=50



Relation between trj and trb